Ultrafast Dual Diode 30 A, 200 V

RURG3020CC

Description

The RURG3020CC is an ultrafast dual diode with low forward voltage drop. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial application.

Features

- Ultrafast Recovery $t_{rr} = 50 \text{ ns } (@ I_F = 30 \text{ A})$
- Max Forward Voltage, $V_F = 1.0 \text{ V}$ (@ $T_C = 25^{\circ}\text{C}$)
- Reverse Voltage, V_{RRM} = 200 V
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

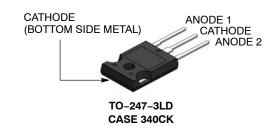
Applications

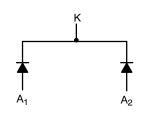
- Switching Power Supplies
- Power Switching Circuits
- General Purpose



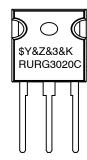
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MARKING DIAGRAM



\$Y = ON Semiconductor Logo &Z = Assembly Plant Code &3 = Numeric Date Code &K = Lot Code

RURG3020C = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

RURG3020CC

ABSOLUTE MAXIMUM RATINGS (Per Leg) ($T_C = 25^{\circ}C$)

Parameter	Symbol	Ratings	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	200	V
Working Peak Reverse Voltage	V_{RWM}	200	V
DC Blocking Voltage	V _R	200	V
Average Rectified Forward Current (Per Leg) (T _C = 145°C)	I _{F(AV)}	30	Α
Repetitive Peak Surge Current (Square Wave, 20 kHz)	I _{FRM}	70	Α
Nonrepetitive Peak Surge Current (Halfwave, 1 Phase, 60 Hz)	I _{FSM}	325	Α
Maximum Power Dissipation	P _D	125	W
Avalanche Energy (See Figures 7 and 8)	E _{AVL}	20	mJ
Operating and Storage Temperature	T _{STG} , T _J	-65 to 175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

PACKAGE MARKING AND ORDERING INFORMATION

Device	Device Marking	Package	Shipping
RURG3020CC	RURG3020C	TO-247-3LD	450 / Tube

ELECTRICAL SPECIFICATION (Per Leg) (T_C = 25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Instantaneous Forward Voltage (Pulse Width = 300 μs, Duty Cycle = 2%)	V _F	I _F = 30 A	-	_	1.0	V
		I _F = 30 A, T _C = 150°C	-	-	0.85	V
Instantaneous Reverse Current	I _R	V _R = 200 V	-	-	250	μΑ
		V _R = 200 V, T _C = 150°C	-	-	1	mA
Reverse Recovery Time (See Figure 6)	t _{rr}	$I_F = 1 \text{ A, } dI_F/dt = 100 \text{ A/}\mu\text{s}$	-	_	45	ns
Summation of t _a + t _b		$I_F = 30 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	_	50	ns
Time to Reach Peak Reverse Current (See Figure 6)	t _a	$I_F = 30 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	20	-	ns
Time from Peak I _{RM} to Projected Zero Crossing of I _{RM} Based on a Straight Line from Peak I _{RM} through 25% of I _{RM} (See Figure 6)	t _b	$I_F=30$ A, $dI_F/dt=100$ A/ μs	-	15	_	ns
Thermal Resistance Junction to Case	$R_{ heta JC}$		-	_	1.2	°C/W

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

RURG3020CC

TYPICAL PERFORMANCE CURVES

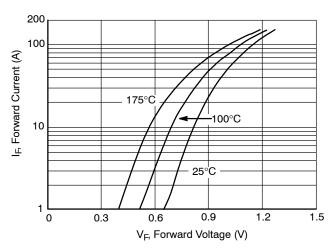


Figure 1. Forward Current vs. Forward Voltage

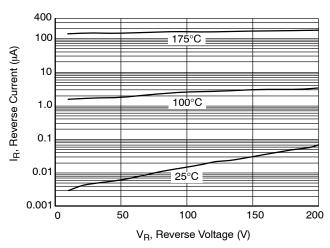


Figure 2. Reverse Current vs. Reverse Voltage

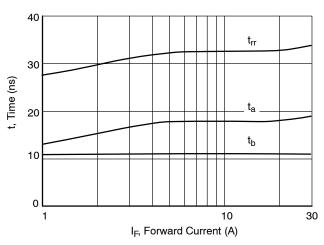


Figure 3. t_{rr} , t_a and t_b Curves vs. Forward Current

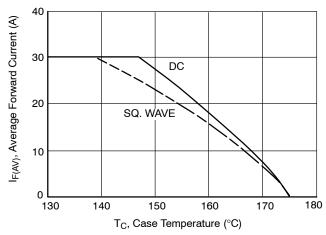
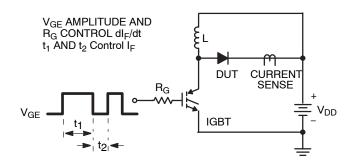


Figure 4. Current Derating Curve

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TEST CIRCUITS AND WAVEFORMS



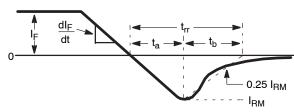


Figure 5. t_{rr} Test Circuit

Figure 6. t_{rr} Waveforms and Definitions

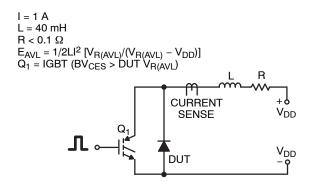


Figure 7. Avalanche Energy Test Circuit

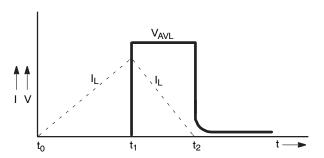
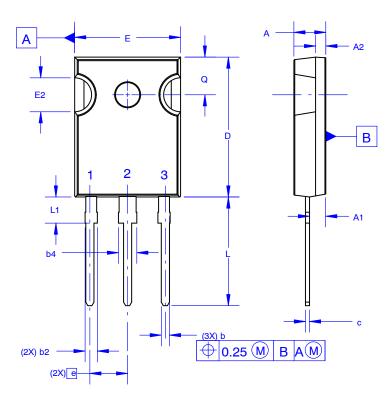


Figure 8. Avalanche Current and Voltage Waveforms

TO-247-3LD SHORT LEAD

CASE 340CK ISSUE A





- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 2009.
- D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code

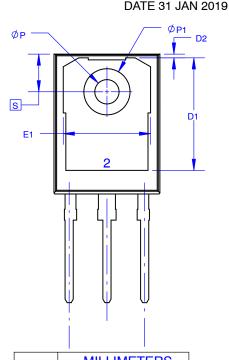
A = Assembly Location

Y = Year

WW = Work Week

ZZ = Assembly Lot Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



DIM	MILLIMETERS			
DIIVI	MIN	NOM	MAX	
Α	4.58	4.70	4.82	
A1	2.20	2.40	2.60	
A2	1.40	1.50	1.60	
b	1.17	1.26	1.35	
b2	1.53	1.65	1.77	
b4	2.42	2.54	2.66	
С	0.51	0.61	0.71	
D	20.32	20.57	20.82	
D1	13.08	~	~	
D2	0.51	0.93	1.35	
E	15.37	15.62	15.87	
E1	12.81	~	~	
E2	4.96	5.08	5.20	
е	~	5.56	~	
L	15.75	16.00	16.25	
L1	3.69	3.81	3.93	
ØΡ	3.51	3.58	3.65	
ØP1	6.60	6.80	7.00	
Q	5.34	5.46	5.58	
S	5.34	5.46	5.58	

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